

HIGH VOLTAGE POWER SWITCH

... designed for horizontal deflection output stage of CTV receivers and high voltage, fast s witching and induatrial application.

FEATURES

* Collector-Emitter Sustaining Voltage-100 mA V_{CEO(sus)}= 400V (Min) BUY69A 325V (Min) BUY69B 200V (Min) BUY69C

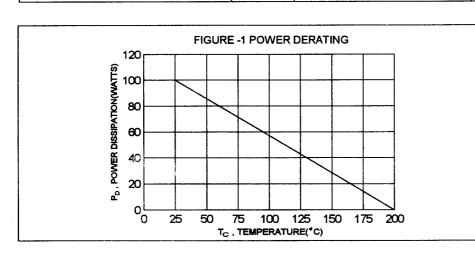
* Optimum Drive Condition Curves

MAXIMUM RATINGS

| Characteristic | Symbol | BUY69A | BUY69B | BUY69C | Unit |
|---|----------------------------------|-------------|-------------|--------|------|
| Collector-Emitter Voltage(V _{BE} =0) | V _{CBS} | 1000 | 800 | 500 | ٧ |
| Collector-Emitter Voltage | V _{CEO} | 400 | 325 | 200 | ٧ |
| Emitter-Base Voltage | V _{EBO} | 8.0 | | ٧ | |
| Collector Current - Continuous - Peak | I _C | 10 15 | | A | |
| Base Current-Peak | l _B | 3.0 | | Α | |
| Total Power Dissipation @T _c = 25°C Derate above 25°C | P _D | 100 0.57 | | W/°C | |
| Operating and Storage Junction Temperature Range | T _J ,T _{STG} | | -65 to +200 | | °C |

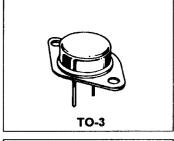
THERMAL CHARACTERISTICS

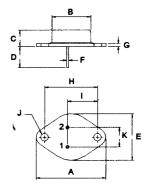
| Characteristic | Symbol | Max | UNIT | | |
|-------------------------------------|--------|------|------|--|--|
| Thermal Resistance Junction to Case | Rθjc | 1.75 | °C/W | | |



NPN BUY69A BUY69B BUY69C

10 AMPERE SILICON POWER TRANSISTORS 200-400 VOLTS 100 WATTS





PIN 1.BASE 2.EMITTER COLLECTOR(CASE)

| DIM | MILLIMETERS | | | |
|-------|-------------|-------|--|--|
| Dilvi | MIN | MAX | | |
| Α | 38.75 | 39.96 | | |
| В | 19.28 | 22.23 | | |
| С | 7.96 | 9.28 | | |
| D | 11.18 | 12.19 | | |
| E | 25.20 | 26.67 | | |
| F | 0.92 | 1.09 | | |
| G | 1.38 | 1.62 | | |
| Н | 29.90 | 30.40 | | |
| ı | 16.64 | 17.30 | | |
| J | 3.88 | 4.36 | | |
| K | 10.67 | 11.18 | | |

| ELECTRICAL | . CHARACTERISTICS | $(T_c = 25^{\circ}C \text{ unless})$ | otherwise noted) |
|------------|-------------------|--------------------------------------|------------------|
|------------|-------------------|--------------------------------------|------------------|

| Characteristic | | Symbol | Min | Max | Unit | |
|---|----------------------------|-----------------------|--------------------|-------------------|------|--|
| OFF CHARACTERISTICS | | | | | | |
| Collector-Emitter Sustaining Voltage(1) (I _C = 100 mA, I _B = 0) | BUY69A BUY69B BUY69C | V _{CEO(sus)} | 400 325 200 | | V | |
| Collector-Base Voltage (I _C = 1.0 mA, I _E = 0) | BUY69A BUY69B BUY69C | V _{CBO} | 1000 800 500 | | V | |
| Collector Cutoff Current (V _{CE} = 1000 V, V _{BE} =0) (V _{CE} = 800 V , V _{BE} =0) (V _{CE} = 500 V , V _{BE} =0) | BUY69A BUY69B BUY69C | I _{CES} | | 1.0 1.0 1.0 | mA | |
| Emitter -Base Cutoff Current (V _{EB} = 8.0 V, I _C = 0) | | I _{EBO} | | 1.0 | mA | |

| DC Current Gain (V _{CE} = 10 V, I _C =2.5 A) | h _{FE} | 15 | | |
|--|----------------------|----|-----|---|
| Collector-Emitter Saturation Voltage (I _C =8.0 A,I _B = 2.5 A) | V _{CE(sat)} | | 3.3 | V |
| Base-Emitter Saturation Voltage (I _C =8.0 A, I _B = 2.5 A) | V _{BE(sat)} | | 2.2 | ٧ |

DYNAMIC CHARACTERISTICS

| Current Gain-Bandwidth Product (2) | f _T | | MHz |
|---|----------------|----|-----|
| (I _C = 500 mA, V _{CE} = 10 V,f = 1MHz) | • | 10 | |

SWITCHING CHARACTERISTICS

| Rise Time | V _{CC} = 250V,I _C = 5A | tr | 0.3 | us |
|--------------|--|----------------|-----|----|
| Storage Time | I _{B1} =-I _{B2} = 1.0A | ts | 1.8 | us |
| Fall Time | | t _f | 1.0 | us |

⁽¹⁾ Pulse Test: Pulse width = 300 us , Duty Cycle ≤ 2.0%

⁽²⁾ $f_T = |h_{fe}| \cdot f_{test}$



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